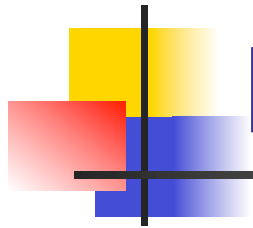


3.003



Principles of Engineering Practice

- One Month Review
- Solar Cells
 - The Sun
 - Semiconductors
 - pn junctions
 - Electricity



Engineering Practice

1. Problem Definition
2. Constraints
3. Options
4. Analysis
5. Solution



Tool Box (1): Wave Equation

dielectric constant and index of refraction

Wave equation

$$\nabla^2 U - \frac{1}{c_0^2} \frac{\partial^2 U}{\partial t^2} = 0$$

time and spatial variation

n = index of refraction

= c_0/c = 1 (vacuum)

= $(\epsilon/\epsilon_0)^{1/2}$ (in a material)

$$c_0 = (\epsilon_0 \mu_0)^{-1/2} = 3 \times 10^8 \text{ m/s}$$

ϵ_0 = permittivity of free space

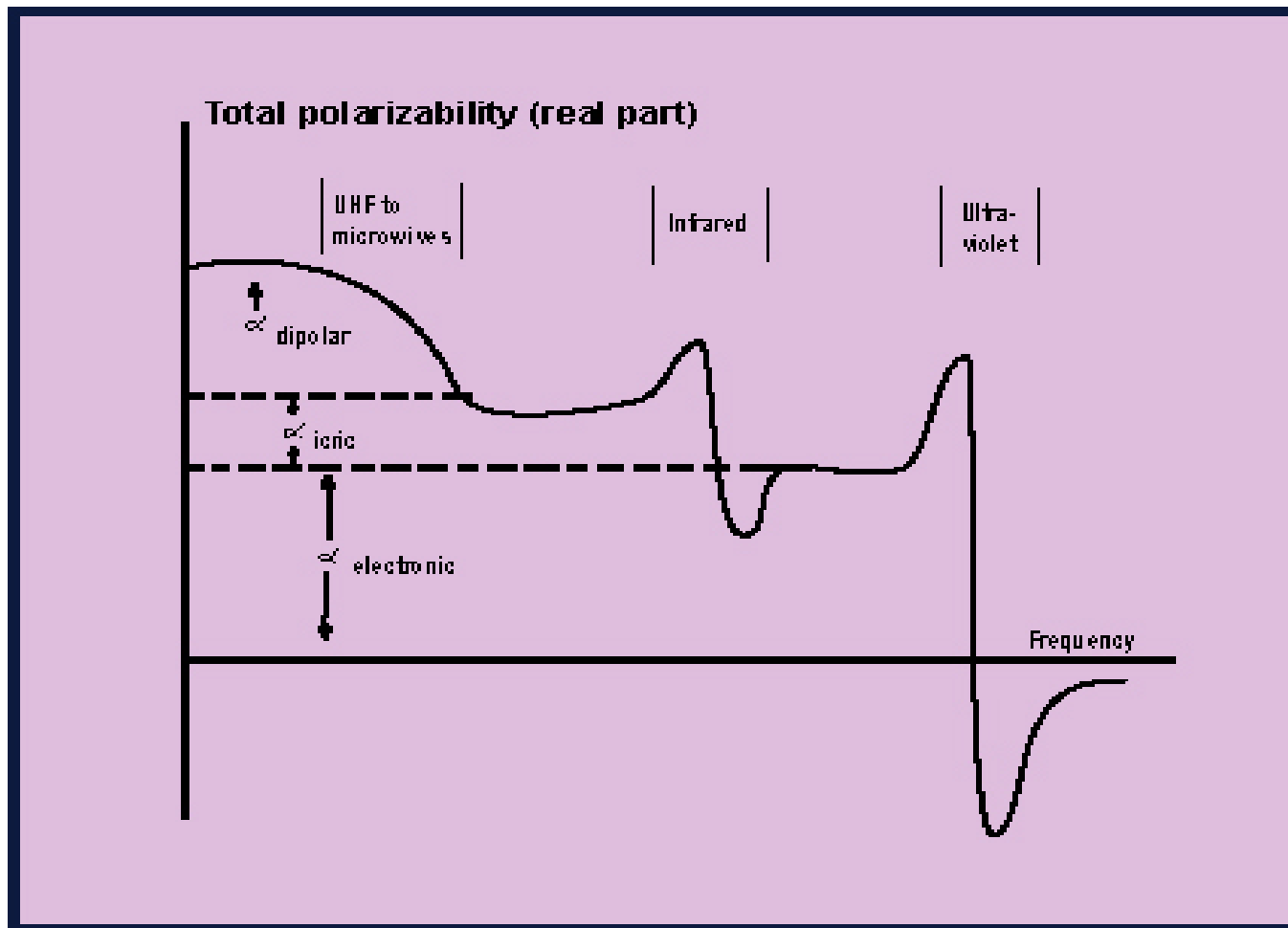
$$= \frac{1}{36\pi} \times 10^{-9} \text{ Fm}^{-1} \quad (\text{MKS})$$

μ_0 = magnetic permeability of free space

$$= 4\pi \times 10^{-7} \text{ Hm}^{-1} \quad (\text{MKS})$$

$$\epsilon_0 \mu_0 c_0^2 = 1$$

Polarizability, Dielectric Constant, Refractive Index



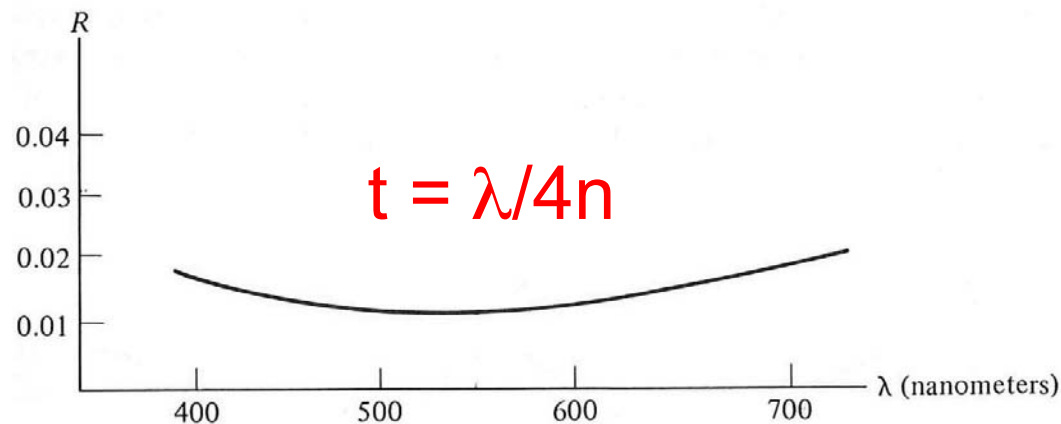
Anti-Reflection Coating Design

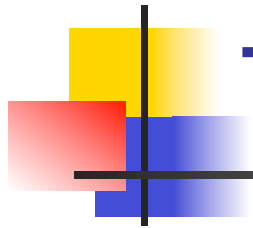
- Set $R=0$

$$n_1 = (n_0 n_2)^{1/2}$$

(index of middle layer is geometric mean of other two indices)

- Sensitivity analysis: $f(\lambda, t, n)$





The Solar Cell

- 1) Principles of operation
- 2) Relevant performance metrics
- 3) Design for performance
- 4) Design for manufacturing
- 5) Design for application
- 6) Scale of production

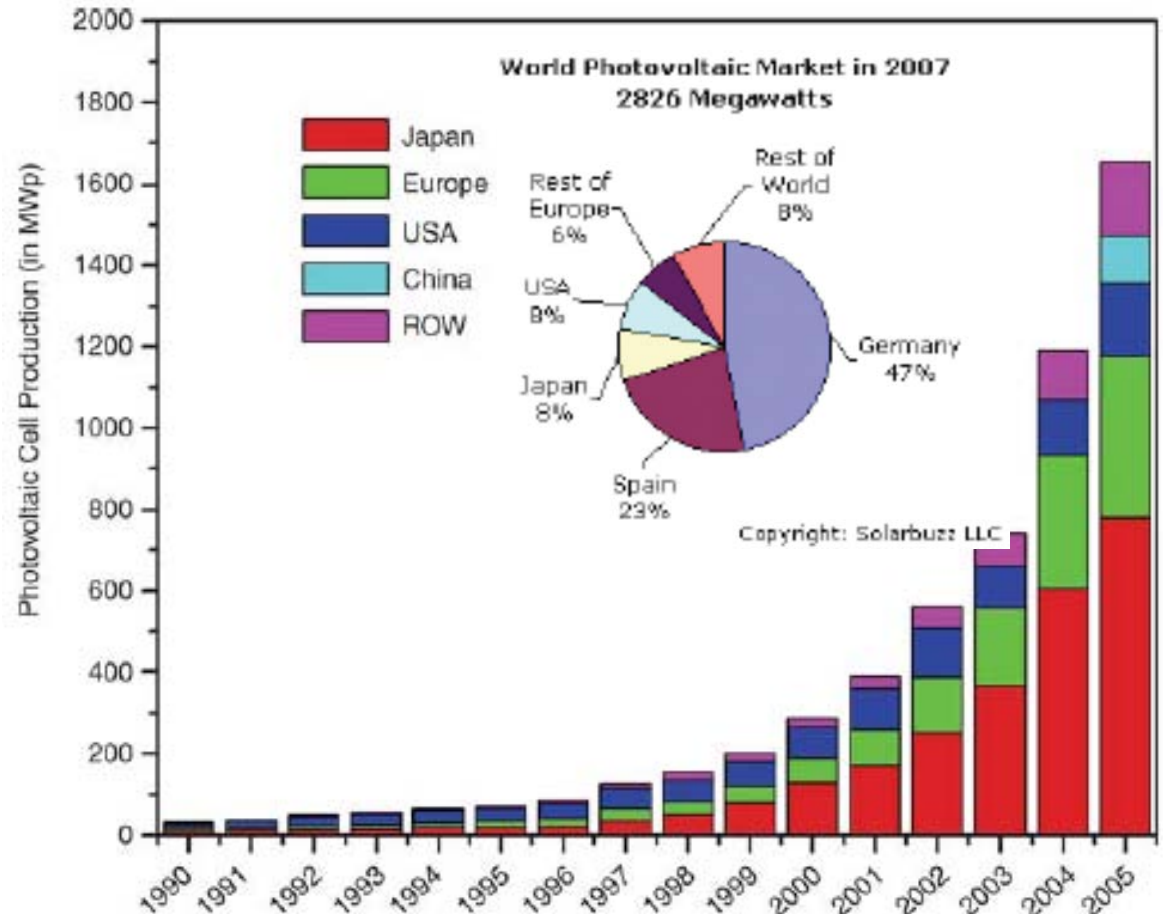
Environmental and Market Driving Forces for Solar Cells



Greenhouse Gases (g/ kWh of CO₂ equivalent)

Coal	900
Oil	850
Natural Gas	400
Biomass	45
PV (Bulk Si)	37
PV (Thin Film)	18
Nuclear	24
Wind	11

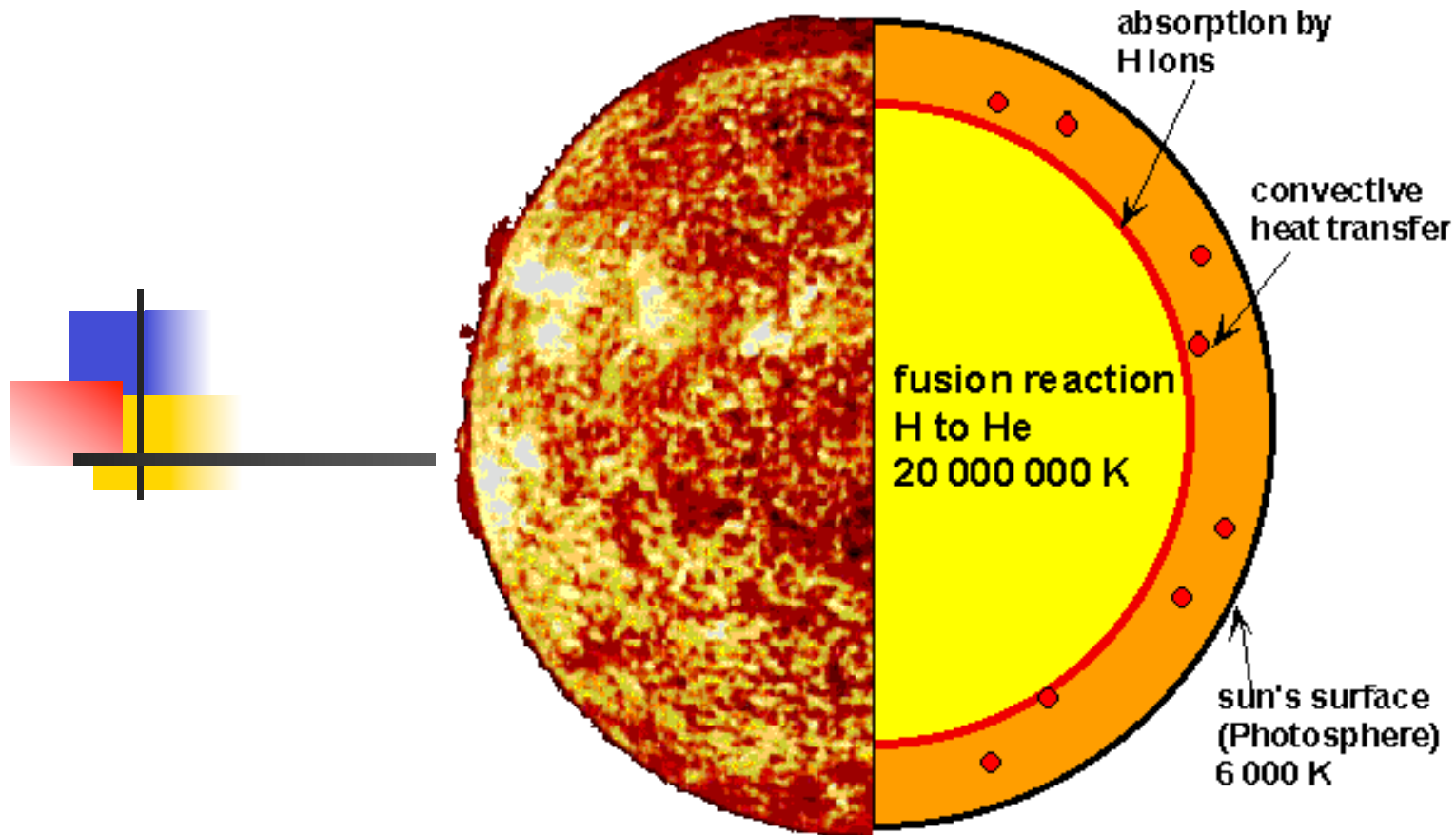
V. Fthenakis & H.C. Kim, Brookhaven National L
W. Beckman, University of Wisconsin-Madison.



Courtesy of Solarbuzz LLC. Used with permission.

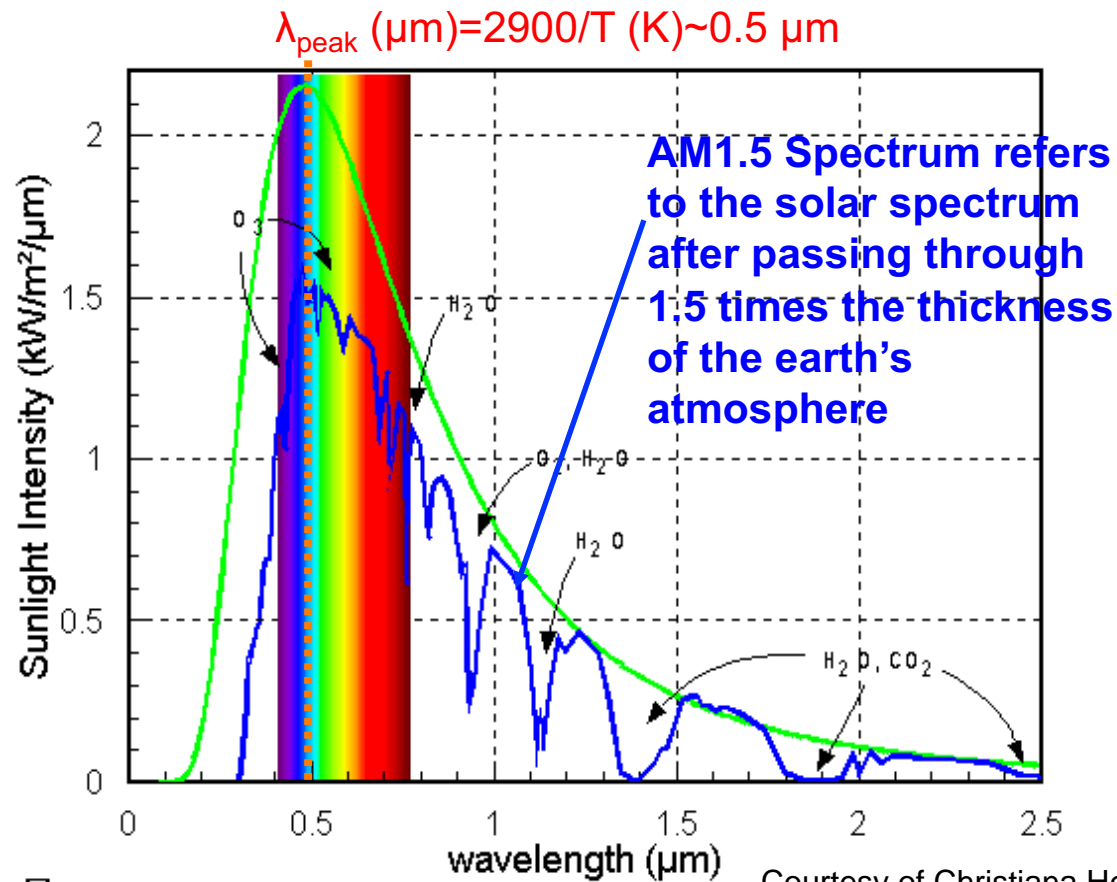
- Solar cells are environmental friendly energy sources.
- Solar electricity generation was 2.8 GW power in 2007 (1.8 GW in 2006).
- World's market for solar cells grew 62% in 2007 (50% in 2006). Revenue reached \$17.2 billion. (26% growth predicted for 2009 despite recession).

The Sun

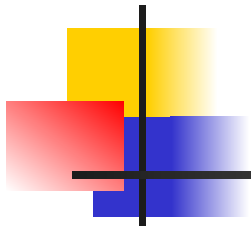


- Sun powered by nuclear fusion. Surface temperature ~5800 K
- Will last another 5 billion years!

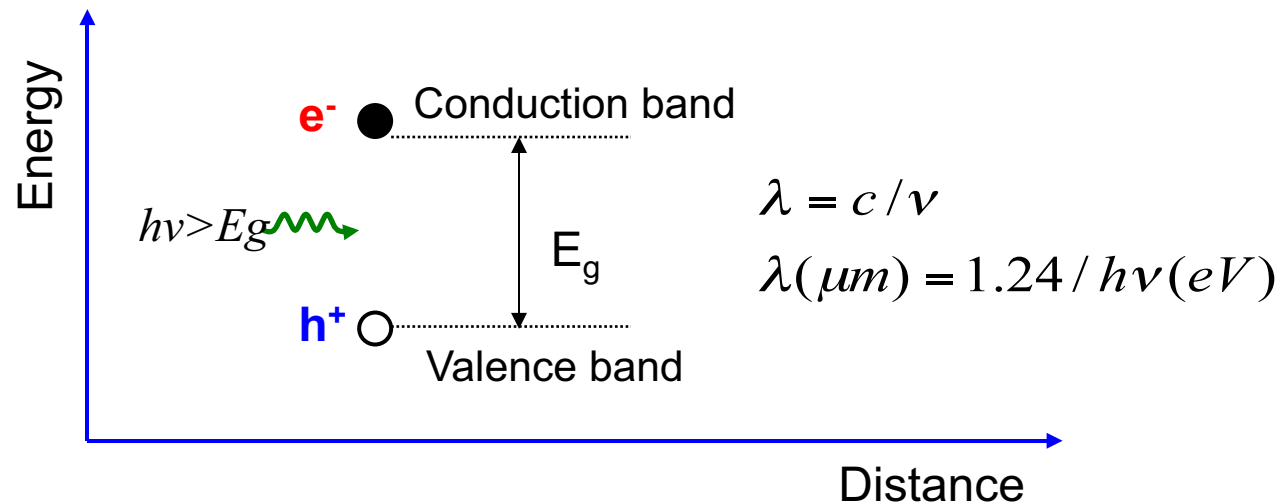
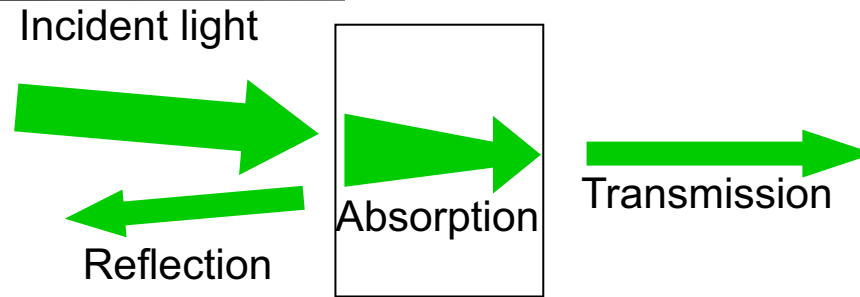
The Solar Spectrum



- Solar spectrum on earth is black body radiation modified by molecular absorption in the atmosphere.
- Power density $\sim 0.9 \text{ kW/m}^2$ on a sunny day.
- Total energy delivered to earth $\sim 10^{18} \text{ kWh/year}$ (8000x global energy consumption)!



Light-Matter Interaction



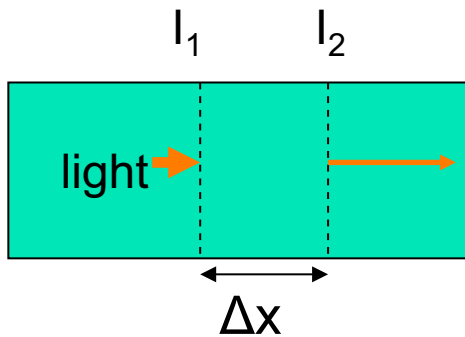
Absorption (A) + Reflection (R) + Transmission (T) = 1
Absorb the incident light in order to harvest optical energy.
Minimize reflection helps to maximize absorption
Photon energy (hc/λ) > band gap (E_g) to be absorbed

Does a blue semiconductor exist?



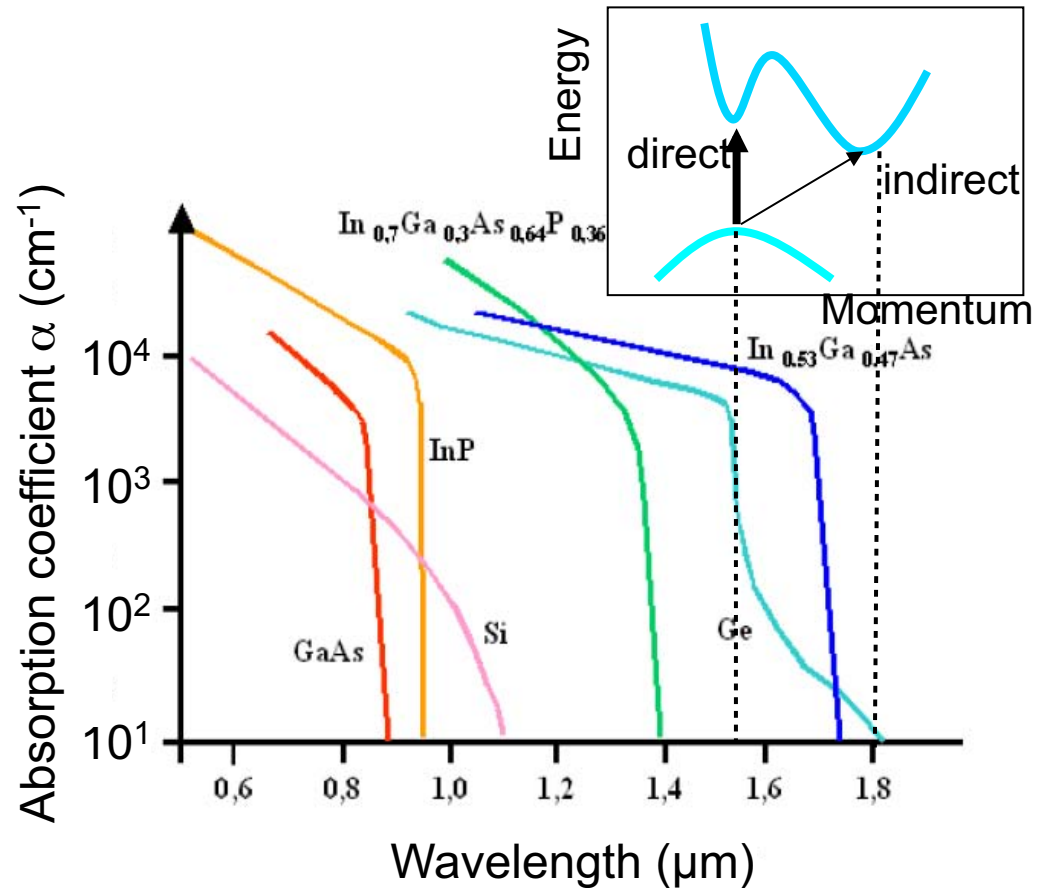
Absorption Spectra of Semiconductors

α = Absorption Coefficient



$$dI / dx = -\alpha I$$

$$I_2 = I_1 \exp(-\alpha \Delta x)$$

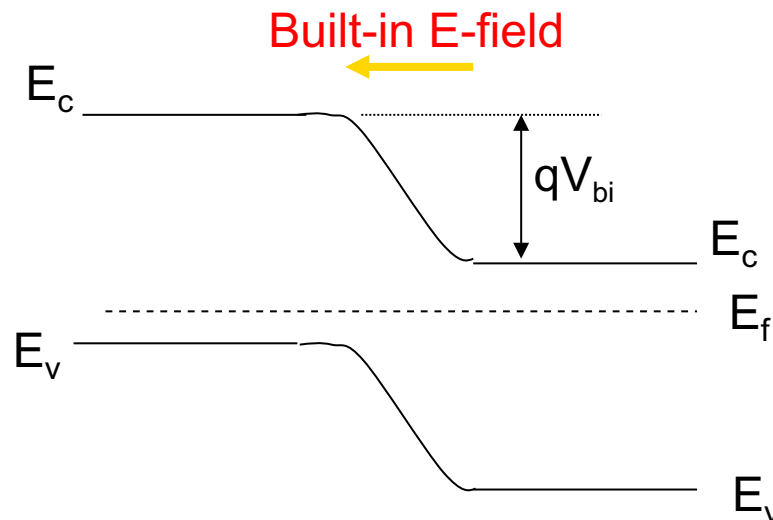
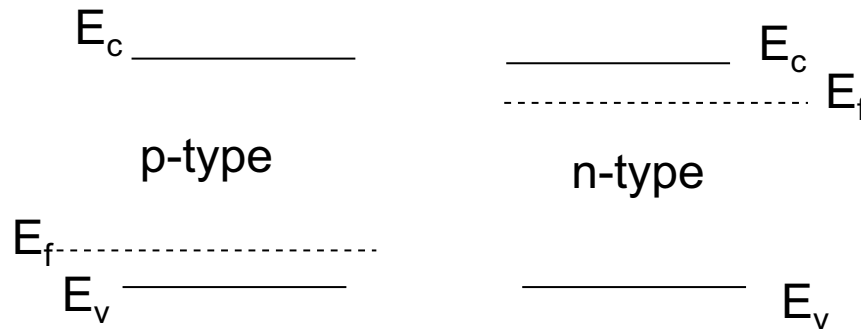


Courtesy of Helmut Föll. Used with permission.

- **Absorption Coefficient (α)** defines the material's absorbed optical power.
- **Direct gap materials** have a much higher α

Tool Box (3): The pn junction

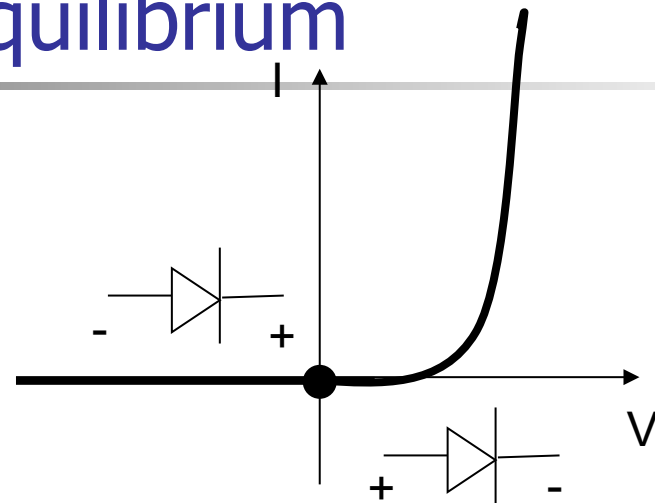
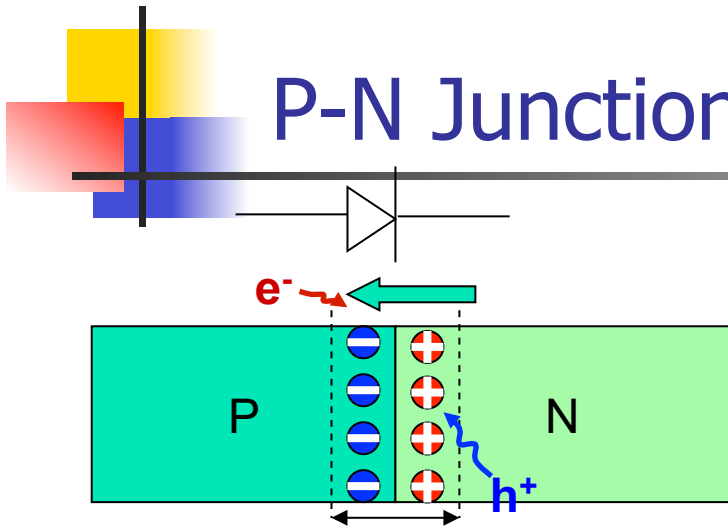
Solar Battery Voltage



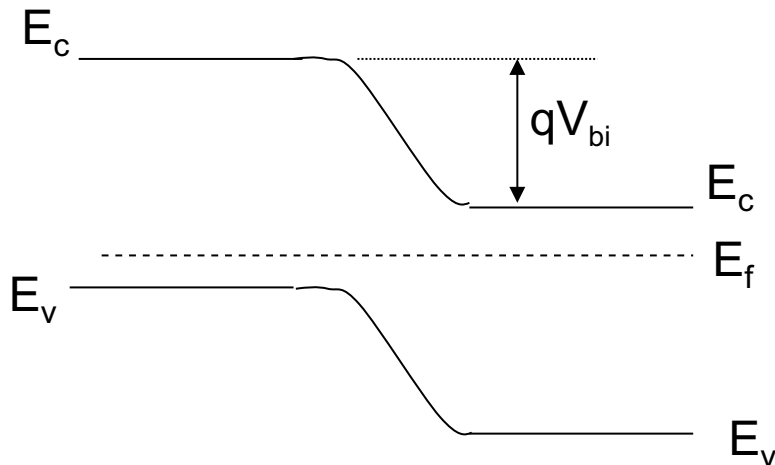
- The potential is the **electrochemical potential of the electron**, known as the Fermi level, E_f .
- $E_f = kT \ln (n/N_c)$
 - n = electron concentration
 - N_c = 'density of states'
= empty states at E_c

When two dissimilar materials contact, charge flows to equalize the chemical potential. This charge exchange creates the voltage to drive current under illumination.

P-N Junction at Equilibrium



Built-in E-field



Reverse current:

Any **minority carriers** (e^- in p-type semiconductor or h^+) can drift under the built-in electric field and induce a reverse current $-I_0$

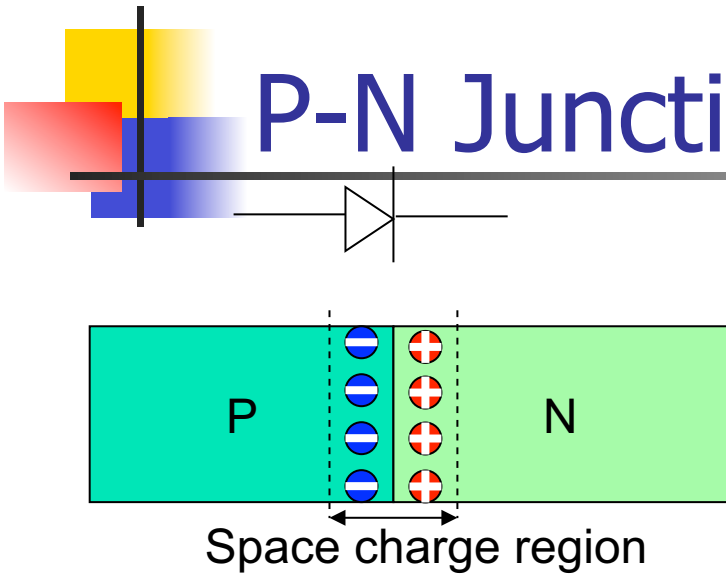
$$I_0 \propto \text{minority carrier density} \propto n_{p0}, p_{n0}$$

$$n_i^2 \propto \exp(-E_g / kT)$$

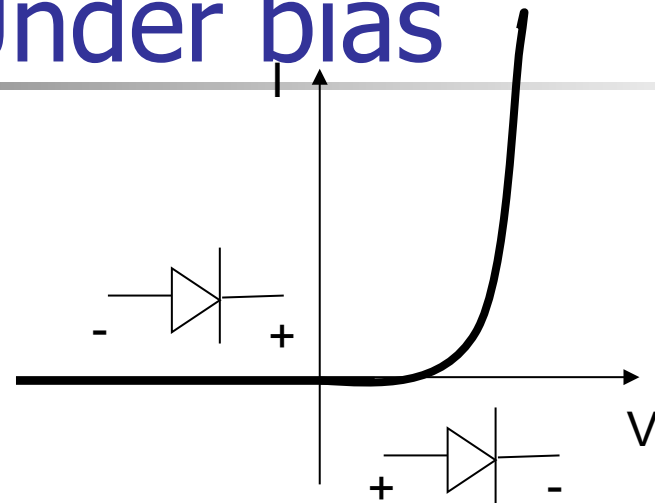
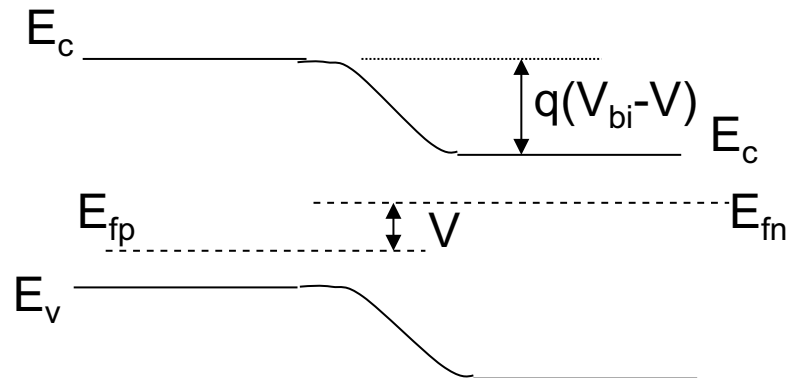
Forward current:

At equilibrium the net current is 0, so the forward current must be I_0

P-N Junction Under bias



Built-in E-field



Apply a bias of V :

Forward current:

The potential barriers for majority carriers is modified by an amount of qV compared to 0 bias, so the forward current is modified by a factor of $\exp(qV/kT)$: Boltzman distribution .

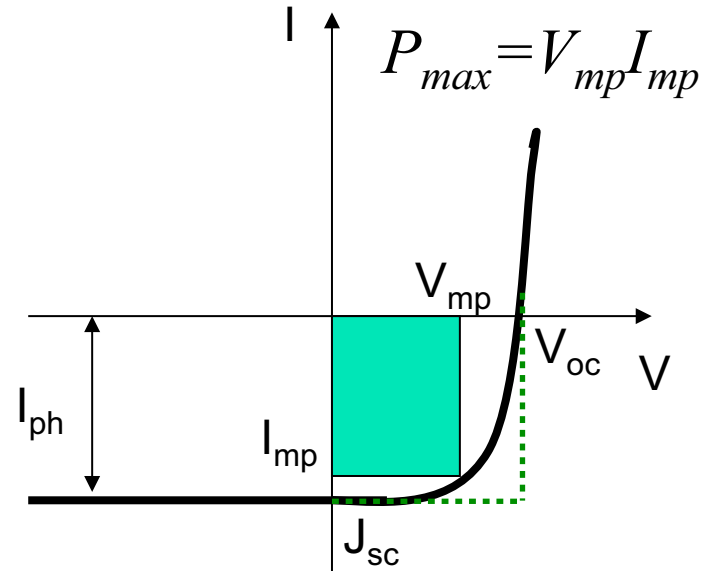
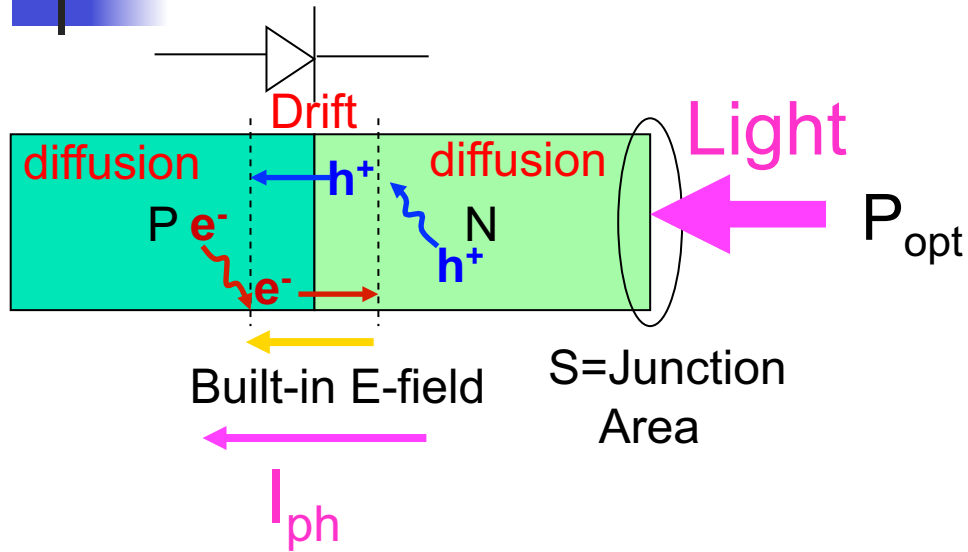
Therefore $I_{forward} = I_0 \exp(qV/kT)$

E_f **Reverse current**

The same as 0 bias: $-I_0$

$$I = I_0 \left[\exp(qV / kT) - 1 \right]$$

Photocurrent: P-N Junction under Illumination



$$I = I_0 \left[\exp(qV / kT) - 1 \right] - I_{ph};$$

$$I_{sc} = I_{ph}; \quad V_{oc} = (kT / q) \ln(1 + I_{ph} / I_0) \approx (kT / q) \ln(I_{ph} / I_0)$$

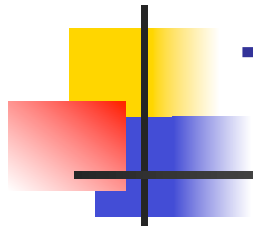
$$\text{Fill Factor (FF)} = V_{mp} J_{mp} / V_{oc} J_{sc} \sim 0.6-0.8$$

$$\text{Energy conversion efficiency, } \eta_{\text{energy}} = \text{FF} * V_{oc} * J_{sc} / P_{\text{opt}}$$



Solar Cells Devices

- Solar radiation spectrum is close to black-body radiation (broad spectrum)
- The photon energy needs to be absorbed by the semiconductor material.
 - Selection of band gaps is important for solar cells
- The pn junction potential drives current flow to create electrical power.



The Solar Cell

- 1) Principles of operation
- 2) Relevant performance metrics
- 3) Design for performance
- 4) Design for manufacturing
- 5) Design for application
- 6) What scale of production is consistent with (6)?

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3.003 Principles of Engineering Practice
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